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November 2013



SGH40N60UF

General Description

Fairchild's UF series IGBTs provide low conduction and switching losses. UF series is designed for the applications such as general inverter and PFC where high speed switching is required feature.

Features

- High Speed Switching
- Low Saturation Voltage: $V_{CE(sat)} = 2.1 \text{ V} @ I_C = 20 \text{ A}$
- High Input Impedance

Application

· General Inverter, PFC







Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Description		Ratings	Unit
V _{CES}	Collector-Emitter Voltage		600	V
V _{GES}	Gate-Emitter Voltage		± 20	V
	Collector Current	$@T_{C} = 25^{\circ}C$	40	Α
IC	Collector Current	@ T _C = 100°C	20	Α
I _{CM (1)}	Pulsed Collector Current		160	Α
P _D	Maximum Power Dissipation	$@T_{C} = 25^{\circ}C$	160	W
	Maximum Power Dissipation	@ T _C = 100°C	64	W
TJ	Operating Junction Temperature		-55 to +150	°C
T _{stg}	Storage Temperature Range		-55 to +150	°C
TL	Maximum Lead Temp. for Soldering Purposes, 1/8" from Case for 5 Seconds		300	°C

Notes :

(1) Repetitive rating : Pulse width limited by max. junction temperature

Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Unit
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case		0.77	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient		40	°C/W

Electrical Characteristics of the IGBT $T_C = 25^{\circ}\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Off Chai	racteristics					
BV _{CES}	Collector-Emitter Breakdown Voltage	$V_{GE} = 0 \text{ V, } I_{C} = 250 \text{ uA}$	600			V
ΔB _{VCES} / ΔΤ _J	Temperature Coefficient of Breakdown Voltage	V _{GE} = 0 V, I _C = 1 mA		0.6		V/°C
I _{CES}	Collector Cut-Off Current	$V_{CE} = V_{CES}, V_{GE} = 0 V$			250	uA
I _{GES}	G-E Leakage Current	$V_{GE} = V_{GES}, V_{CE} = 0 V$			± 100	nA
On Chai	racteristics					
V _{GE(th)}	G-E Threshold Voltage	$I_C = 20 \text{ mA}, V_{CE} = V_{GE}$	3.5	4.5	6.5	V
	Collector to Emitter	$I_C = 20 \text{ A}, V_{GF} = 15 \text{ V}$		2.1	2.6	V
V _{CE(sat)}	Saturation Voltage	I _C = 40 A, V _{GE} = 15 V		2.6		V
Dynami	c Characteristics					
C _{ies}	Input Capacitance	V 00.V.V 0.V		1430		pF
C _{oes}	Output Capacitance	$V_{CE} = 30 \text{ V}, V_{GE} = 0 \text{ V},$		170		pF
C _{res}	Reverse Transfer Capacitance	f = 1 MHz		50		рF
Ores	The state of the s					
	ng Characteristics			1		
Switchir				15		ns
	ng Characteristics					
Switchir	ng Characteristics Turn-On Delay Time	V _{CC} = 300 V, I _C = 20 A,		15	 130	ns
Switchir	ng Characteristics Turn-On Delay Time Rise Time	$R_G = 10 \Omega, V_{GE} = 15 V,$		15 30	 130 150	ns ns
Switchir	ng Characteristics Turn-On Delay Time Rise Time Turn-Off Delay Time			15 30 65		ns ns ns
Switchir td(on) tr td(off) tf	Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time	$R_G = 10 \Omega, V_{GE} = 15 V,$		15 30 65 50	150	ns ns ns
Switchir	Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time Turn-On Switching Loss	$R_G = 10 \Omega, V_{GE} = 15 V,$	 	15 30 65 50 160	150	ns ns ns uJ
Switchir dd(on) tr dd(off) tf Eon Eoff Ets	Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time Turn-On Switching Loss Turn-Off Switching Loss	$R_G = 10 \Omega, V_{GE} = 15 V,$	 	15 30 65 50 160 200	150	ns ns ns uJ uJ
Switchir td(on) tr td(off) tf Eon	Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time Turn-On Switching Loss Turn-Off Switching Loss Total Switching Loss	$R_G = 10 \Omega, V_{GE} = 15 V,$	 	15 30 65 50 160 200 360	150	ns ns ns uJ uJ uJ
Switchin dd(on) tr dd(off) tf Eon Eoff Ets dd(on)	Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time Turn-On Switching Loss Turn-Off Switching Loss Total Switching Loss Turn-On Delay Time	$R_G = 10 \Omega$, $V_{GE} = 15 V$, Inductive Load, $T_C = 25^{\circ}C$ $V_{CC} = 300 V$, $I_C = 20 A$,	 	15 30 65 50 160 200 360 30	150 600	ns ns ns uJ uJ uJ
Switchir dd(on) tr dd(off) tf Eon Eoff Ets dd(on) tr dd(off)	Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time Turn-Off Switching Loss Turn-Off Switching Loss Total Switching Loss Turn-On Delay Time Rise Time	$R_G = 10 \Omega$, $V_{GE} = 15 V$, Inductive Load, $T_C = 25^{\circ}C$		15 30 65 50 160 200 360 30 37	150 600 	ns ns ns uJ uJ ns ns
Switchir dd(on) tr dd(off) tf Eon Eoff Ets dd(on) tr dd(off)	Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time Turn-Off Switching Loss Turn-Off Switching Loss Total Switching Loss Turn-On Delay Time Rise Time Turn-Off Delay Time	$R_G = 10 \Omega$, $V_{GE} = 15 V$, Inductive Load, $T_C = 25^{\circ}C$ $V_{CC} = 300 V$, $I_C = 20 A$,	 	15 30 65 50 160 200 360 30 37 110	150 600 200	ns ns ns uJ uJ ns ns
Switchir td(on) tr td(off) tf Eon Ets td(on) tr	Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time Turn-Off Switching Loss Turn-Off Switching Loss Total Switching Loss Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time	$\begin{aligned} R_G &= 10 \ \Omega, \ V_{GE} = 15 \ V, \\ &\text{Inductive Load}, \ T_C = 25^{\circ}C \end{aligned}$ $\begin{aligned} V_{CC} &= 300 \ V, \ I_C = 20 \ A, \\ R_G &= 10 \ \Omega, \ V_{GE} = 15 \ V, \end{aligned}$	 	15 30 65 50 160 200 360 30 37 110	150 600 200	ns ns ns uJ uJ ns ns ns
Switchir td(on) tr td(off) tf Eon Ets td(on) tr td(off)	Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time Turn-Off Switching Loss Turn-Off Switching Loss Total Switching Loss Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time Turn-Off Delay Time Fall Time Turn-On Switching Loss	$\begin{aligned} R_G &= 10 \ \Omega, \ V_{GE} = 15 \ V, \\ &\text{Inductive Load}, \ T_C = 25^{\circ}C \end{aligned}$ $\begin{aligned} V_{CC} &= 300 \ V, \ I_C = 20 \ A, \\ R_G &= 10 \ \Omega, \ V_{GE} = 15 \ V, \end{aligned}$	 	15 30 65 50 160 200 360 30 37 110 144 310	150 600 200	ns ns ns uJ uJ ns ns ns us uJ uJ us ns us
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Switchir td(on) tr td(off) tf Eon Eoff td(on) tr td(off) tr td(off) tr td(off) tr td(off) tr Eon Eoff Eon	Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time Turn-Off Switching Loss Turn-Off Switching Loss Total Switching Loss Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time Turn-Off Switching Loss Turn-Off Switching Loss Turn-Off Delay Time Fall Time Turn-On Switching Loss Turn-Off Switching Loss Turn-Off Switching Loss	$\begin{split} R_G &= 10~\Omega,~V_{GE} = 15~V,\\ &\text{Inductive Load},~T_C = 25^{\circ}C \end{split}$ $V_{CC} &= 300~V,~I_C = 20~A,\\ R_G &= 10~\Omega,~V_{GE} = 15~V,\\ &\text{Inductive Load},~T_C = 125^{\circ}C \end{split}$ $V_{CE} &= 300~V,~I_C = 20~A,$	 	15 30 65 50 160 200 360 30 37 110 144 310 430 740	150 600 200 250 1200	ns ns ns ns uJ uJ ns ns ns us
Switchin td(on) tr td(off) tf Eon Ets td(off) tr td(off) tr td(off) tr td(off) tr td(off) tr Eon Eon Eoff Eon	Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time Turn-Off Switching Loss Turn-Off Switching Loss Total Switching Loss Turn-On Delay Time Rise Time Turn-Off Delay Time Rise Time Turn-Off Delay Time Fall Time Turn-On Switching Loss Turn-On Switching Loss Turn-Off Switching Loss Turn-Off Switching Loss Total Switching Loss Total Switching Loss Total Gate Charge	$\begin{aligned} &R_G=10~\Omega,~V_{GE}=15~V,\\ &\text{Inductive Load},~T_C=25^{\circ}C \end{aligned}$ $\begin{aligned} &V_{CC}=300~V,~I_C=20~A,\\ &R_G=10~\Omega,~V_{GE}=15~V,\\ &\text{Inductive Load},~T_C=125^{\circ}C \end{aligned}$		15 30 65 50 160 200 360 30 37 110 144 310 430 740 97	150 600 200 250 1200 150	ns ns ns uJ uJ ns ns ns us us ns ns ns ns ns

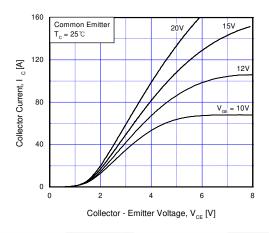
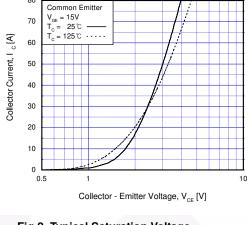


Fig 1. Typical Output Characteristics



80

Fig 2. Typical Saturation Voltage Characteristics

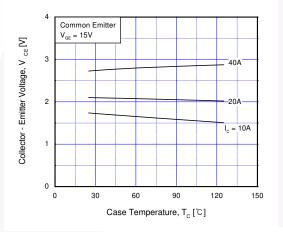


Fig 3. Saturation Voltage vs. Case Temperature at Variant Current Level

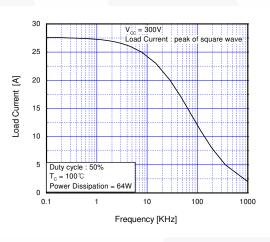


Fig 4. Load Current vs. Frequency

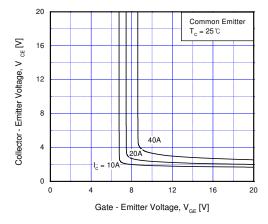


Fig 5. Saturation Voltage vs. V_{GE}

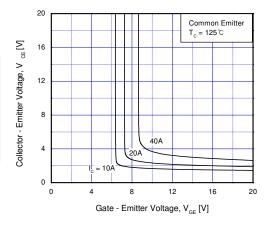


Fig 6. Saturation Voltage vs. V_{GE}

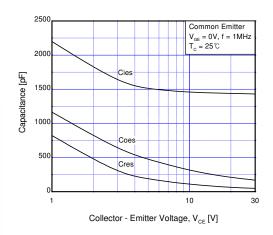


Fig 7. Capacitance Characteristics

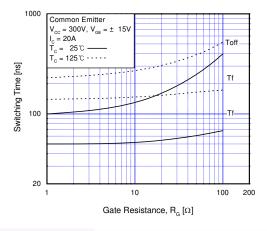


Fig 9. Turn-Off Characteristics vs.
Gate Resistance

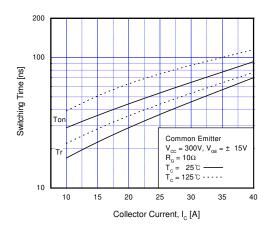


Fig 11. Turn-On Characteristics vs. Collector Current

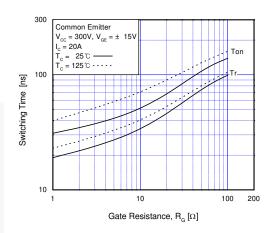


Fig 8. Turn-On Characteristics vs.
Gate Resistance

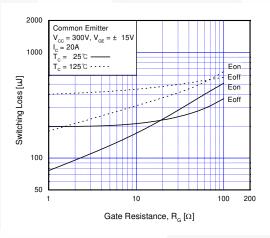


Fig 10. Switching Loss vs. Gate Resistance

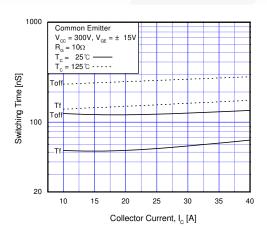


Fig 12. Turn-Off Characteristics vs. Collector Current

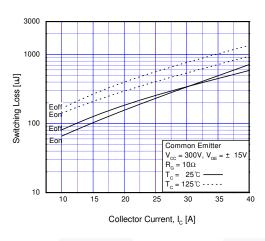


Fig 13. Switching Loss vs. Collector Current

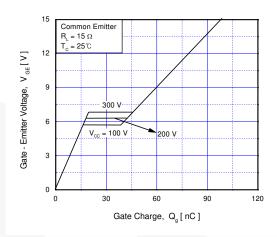


Fig 14. Gate Charge Characteristics

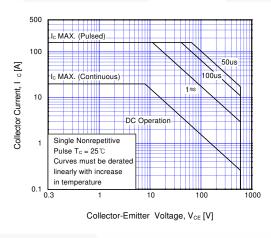


Fig 15. SOA Characteristics

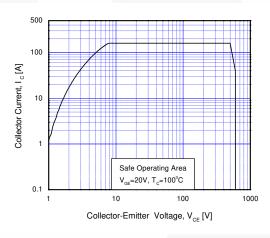


Fig 16. Turn-Off SOA Characteristics

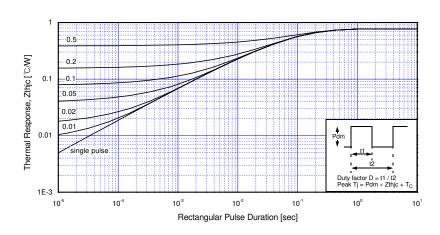


Fig 17. Transient Thermal Impedance of IGBT

Mechanical Dimensions

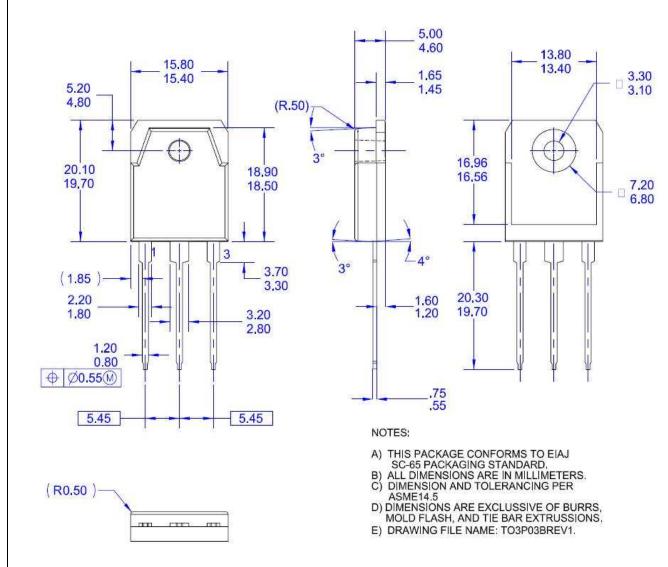


Figure 18. TO-3P 3L - 3LD, T03, PLASTIC, EIAJ SC-65

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No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
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